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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Martin Behringer et al.

Art Unit : Unknown

Serial No. :

Examiner : Unknown

Filed : Herewith

Title : SEMICONDUCTOR COMPONENT CONTAINING LATTICE MISMATCHED
SEMICONDUCTOR MATERIALS**Box PCT**Commissioner for Patents
Washington, D.C. 20231INFORMATION DISCLOSURE STATEMENT

Applicant submits the references listed on the attached form PTO-1449, copies of which are enclosed. A copy of a communication from a foreign patent office in a counterpart application is also enclosed.

This statement is being filed with the application. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

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I hereby certify under 37 CFR §1.10 that this correspondence is being deposited with the United States Postal Service as Express Mail Post Office to Addressee with sufficient postage on the date indicated below and is addressed to the Commissioner of Patents, Washington, D.C. 20231.

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March 15, 2001

Signature

Samantha Bell

Typed or Printed Name of Person Signing Certificate

Samantha Bell

Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 12406-018001	Application No.
	Applicant Martin Behringer et al.		
	Filing Date Herewith	Group Art Unit	

U.S. Patent Documents							
Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,396,103	03/07/1995	OIU et al.			
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AJ							
	AK							
	AL							
	AM							
	AN							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	AO	Magnea, N., "ZnTe fractional monolayers and dots in a CdTe matrix" 6 th International Conference on II-VI Compounds and related optoelectric materials, Journal of Crystal Growth, 138 (1994): 550-558.
	AP	Kutzer, V. et al., "Gain to absorption conversion by increasing excitation density in excitonic waveguides", Journal of Crystal Growth, 184/185 (1998): 632-636.
	AQ	Faschinger, W. et al., "Processes occurring during the formation of graded ZnSe/ZnTe contacts on p-ZnSe", Semicond. Sci. Technol., 12 (1997): 1291-1297.
	AR	Hirose, J. et al., "p-type conductivity control of ZnSe with insertion of ZnTe:Li submonolayers in metalorganic molecular-beam epitaxy", Journal of Applied Physics, 84 (01 DEC 1998): 6100-6104.
	AS	Fan, Y. et al., "Graded band gap ohmic contact to p-ZnSe", Applied Physics Letter, 61 (26), 28 DEC 1992: 3160-3162.

Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	